MMBTH10 TRANSISTOR (NPN)

1.BASE
2.COLLECTOR
3.EMITTER

SOT-23-3

FEATURES

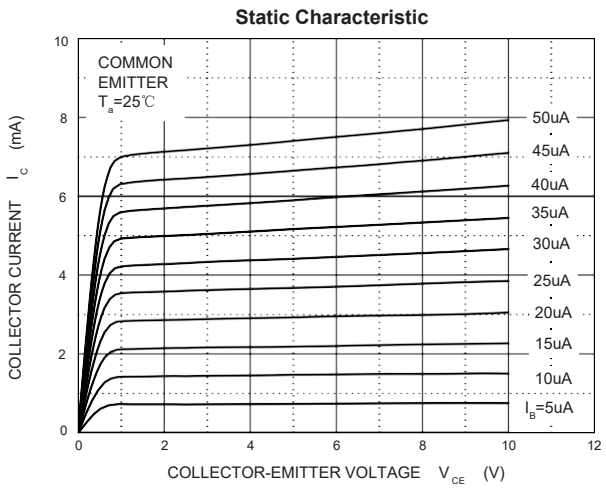
- VHF/UHF Transistor

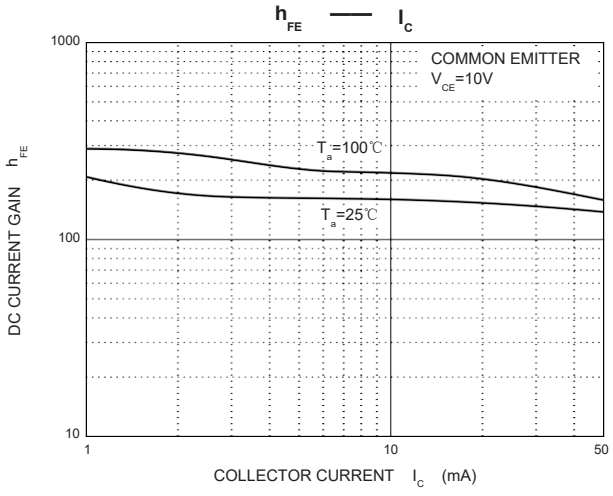
MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

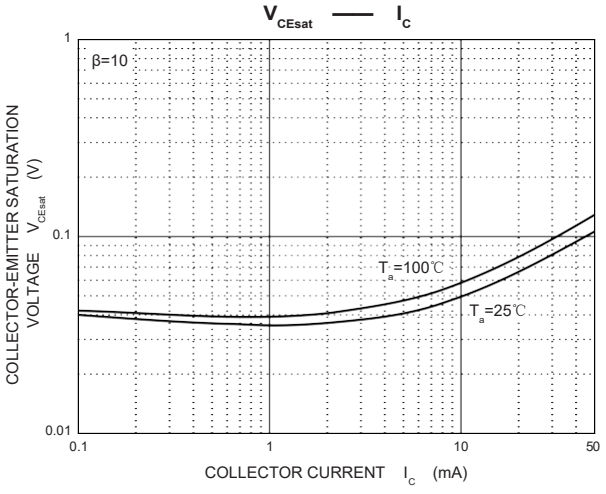
Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	3	V
I_C	Collector Current	50	mA
P_C	Collector Power Dissipation	225	mW
$R_{\Theta JA}$	Thermal Resistance From Junction To Ambient	556	℃/W
T_J,T_{stg}	Operation Junction and Storage Temperature Range	-55～+150	℃

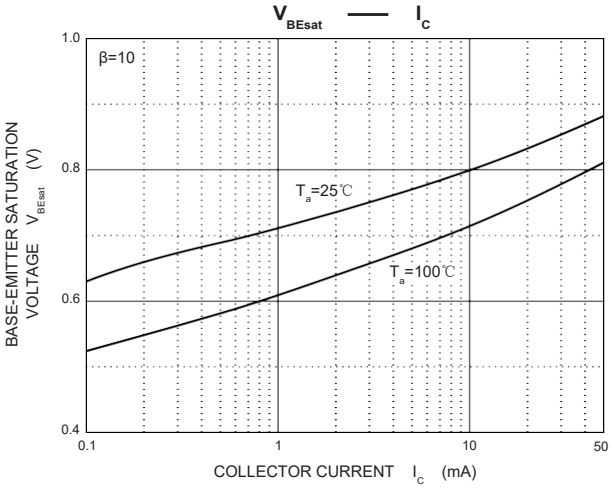
ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

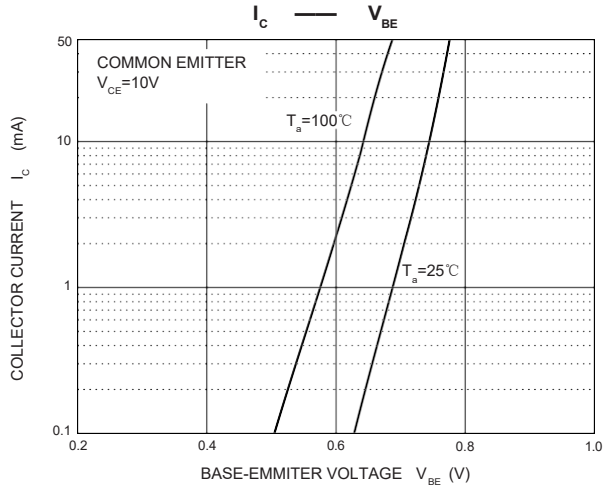
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=100μA, I_E=0	30			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=1mA, I_B=0	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0	3			V
Collector cut-off current	I_{CBO}	V_{CB}=25V, I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}=2V, I_C=0			0.1	μA
DC current gain	h_{FE}	V_{CE}=10V, I_C=4mA	100		200	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=4mA, I_B=0.4mA			0.5	V
Base-emitter voltage	V_{BE}	V_{CE}=10V, I_C=4mA			0.95	V
Transition frequency	f_T	V_{CE}=10V,I_C=4mA f=100MHz	650			MHz
Collector output capacitance	C_{ob}	V_{CB}=10V, I_E=0, f=1MHz			0.7	pF

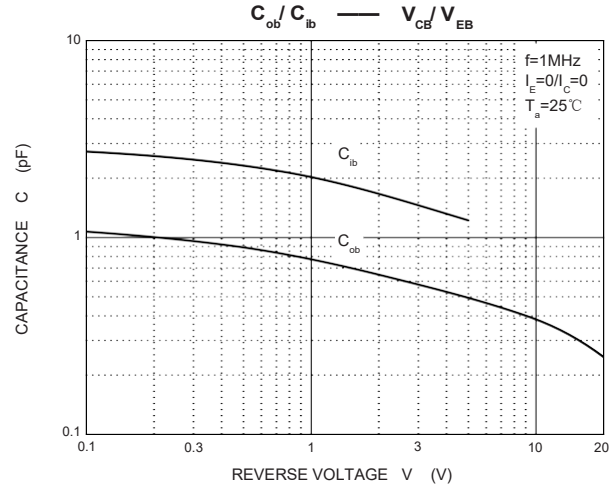

Static Characteristic
COMMON EMITTER
Ta=25℃
50uA
45uA
40uA
35uA
30uA
25uA
20uA
15uA
10uA
IB=5uA
COLLECTOR CURRENT IC (mA)
COLLECTOR-EMITTER VOLTAGE VCE (V)

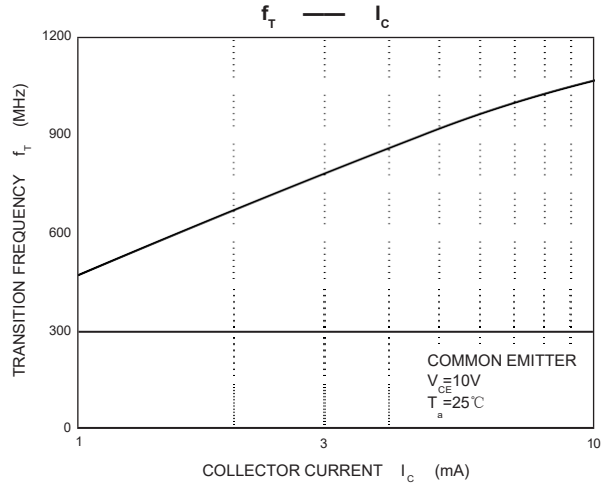

hFE — IC
COMMON EMITTER
VCE=10V
Ta=100℃
Ta=25℃
DC CURRENT GAIN hFE
COLLECTOR CURRENT IC (mA)

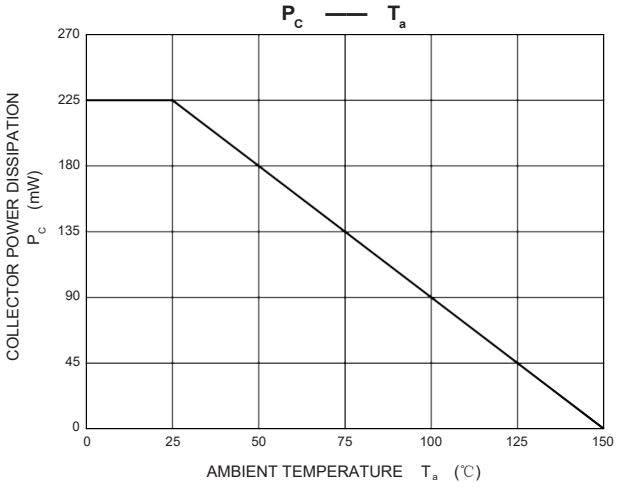

VCEsat — IC
β=10
Ta=100℃
Ta=25℃
COLLECTOR-EMITTER SATURATION VOLTAGE VCEsat (V)
COLLECTOR CURRENT IC (mA)


VBEsat — IC
β=10
Ta=25℃
Ta=100℃
BASE-EMITTER SATURATION VOLTAGE VBEsat (V)
COLLECTOR CURRENT IC (mA)


IC — VBE
COMMON EMITTER
VCE=10V
Ta=100℃
Ta=25℃
COLLECTOR CURRENT IC (mA)
BASE-EMMITER VOLTAGE VBE (V)


Cob/Cib — VCB/VEB
f=1MHz
IE=0/IC=0
Ta=25℃
Cib
Cob
CAPACITANCE C (pF)
REVERSE VOLTAGE V (V)


fT — IC
COMMON EMITTER
VCE=10V
Ta=25℃
TRANSITION FREQUENCY fT (MHz)
COLLECTOR CURRENT IC (mA)


PC — Ta
COLLECTOR POWER DISSIPATION PC (mW)
AMBIENT TEMPERATURE Ta (℃)